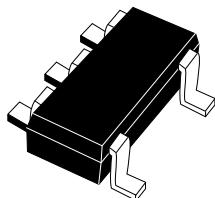


Precision micropower shunt voltage reference



SOT323-5L

Features

- Fixed 2.048 V output voltage
- Ultra low operating current: 10 μ A at 25 °C
- High initial accuracy: $\pm 0.2\%$
- Stable when used with capacitive loads
- Industrial (-40 to +85 °C) temperature range
- 20 ppm / °C typ., 70 ppm / °C max. temperature coefficient
- Available in SOT323-5L package

Applications

- Portable, battery-operated equipment
- Data acquisition systems
- Instrumentation

Description

The TS4061V is a low power high accuracy shunt voltage reference providing a stable output voltage over the industrial temperature range, with a maximum temperature coefficient of 70 ppm/°C.

The SOT323-5L package is ideal in applications where space saving is a critical issue.

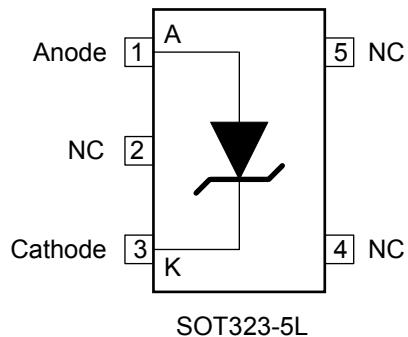
Maturity status link

[TS4061V](#)

The very low operating current is a key advantage for power budgeted designs. In addition, the TS4061V is very stable and can be used in a broad range of application conditions.

1 Pin configuration

Figure 1. Pin connections (top view)



SOT323-5L

Table 1. Order code

Part number	Cathode-to-anode voltage	Precision	Package	Temperature range
TS4061VIBT-205	2.048 V	0.2%	SOT323-5L	-40 to +85 °C

2

Maximum ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
I_k	Reverse breakdown current	20	mA
I_f	Forward current	15	mA
P_d	Power dissipation ⁽¹⁾ SOT323-5L	500	mW
T_{std}	Storage temperature	-65 to +150	°C
ESD	Human body model (HBM)	2	kV
	Charged device model	1500	V
T_{lead}	Lead temperature (Soldering) 10 s.	260	°C
T_j	Max junction temperature	+150	°C

1. P_d has been calculated with $T_{amb} = 25$ °C and $T_{jmax} = 150$ °C

Note: Absolute maximum ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied.

Table 3. Thermal data

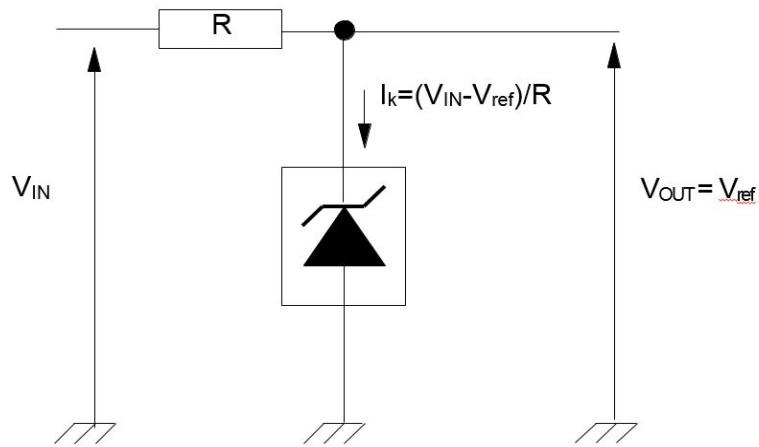
Symbol	Parameter	Value	Unit
R_{thJA}	Thermal resistance junction-ambient	250	°C/W
R_{thJC}	Thermal resistance junction-case	171	°C/W

Table 4. Operating conditions

Symbol	Parameter	Value	Unit
I_{kmin}	Minimum operating current	10	µA
I_{kmax}	Maximum operating current	15	mA
T_{oper}	Operating free air temperature range	-40 to +85	°C

3 Typical application circuit

Figure 2. Application circuit



Note: The value of R must be chosen in order to ensure $I_K \geq I_{Kmin}$ in all the operating conditions (V_{IN} , load and temperature).

4 Electrical characteristics

$I_k = 10 \mu A$, $T_{amb} = 25^\circ C$ (unless otherwise specified).

Table 5. Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
V_k	Initial accuracy TS4061VIBT-205	$I_k = 10 \mu A$	-0.2		+0.2	%
I_{kmin}	Minimum operating current	$T_{amb} = 25^\circ C$		7.5	10	μA
		$-40^\circ C < T_{amb} < +85^\circ C$			12	
$\Delta V_k / \Delta T$	Average temperature coefficient	$10 \mu A < I_k < 15 mA$, $-40^\circ C < T_{amb} < +85^\circ C$		20	70	ppm/ $^\circ C$
$\Delta V_k / \Delta I_k$	Reverse breakdown voltage change with operating current range	$I_{kmin} < I_k < 1 mA$ $-40^\circ C < T_{amb} < +85^\circ C$		0.2	1	mV
		$1 mA < I_k < 15 mA$ $-40^\circ C < T_{amb} < +85^\circ C$			1.7	
R_{ka}	Static impedance	$I_k = 10 \mu A$ to $10 mA$		0.15	0.3	Ω
Hys	Thermal hysteresis	$I_k = 10 \mu A$		120		ppm
Noise	Wide band noise	$I_k = 10 \mu A$ $10 Hz < f < 10 kHz$		90		μV_{RMS}
	Low frequency noise	$I_k = 10 \mu A$ $0.1 Hz < f < 10 Hz$		45		μV_{p-p}

Note: Limits are 100% production tested at $25^\circ C$. Limits overtemperature are guaranteed through correlation and by design.

5 Typical performance characteristics

The following plots are referred to the typical application circuit and, unless otherwise noted, at $T_A = 25^\circ\text{C}$.

Figure 3. Cathode voltage vs. temperature ($I_K = 10 \mu\text{A}$)

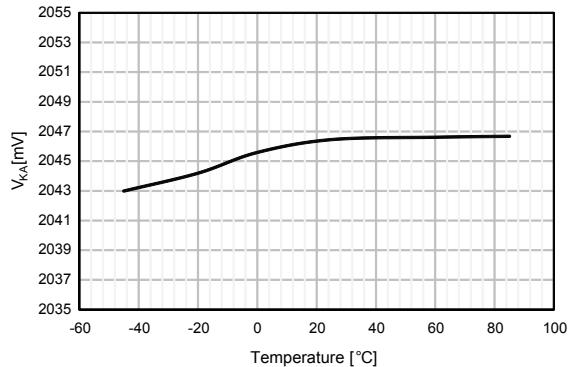


Figure 4. Cathode voltage vs. temperature ($I_K = 1 \text{ mA}$)

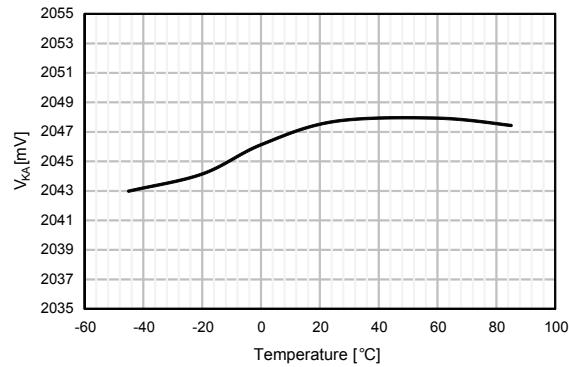


Figure 5. Cathode voltage vs. temperature ($I_K = 15 \text{ mA}$)

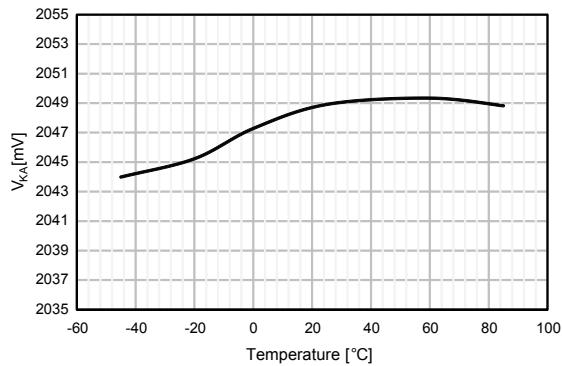


Figure 6. Static impedance vs. temperature

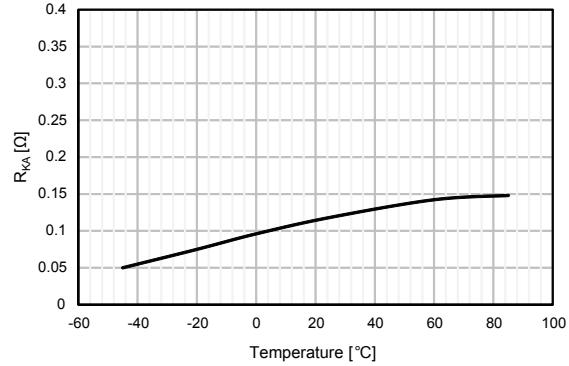


Figure 7. $\Delta V_K / \Delta I_K$ vs. temperature ($I_K = 8 \mu\text{A} \text{ to } 1 \text{ mA}$)

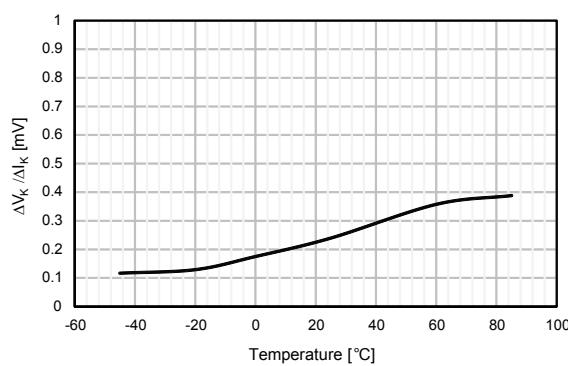


Figure 8. $\Delta V_K / \Delta I_K$ vs. temperature ($I_K = 1 \text{ mA} \text{ to } 15 \text{ mA}$)

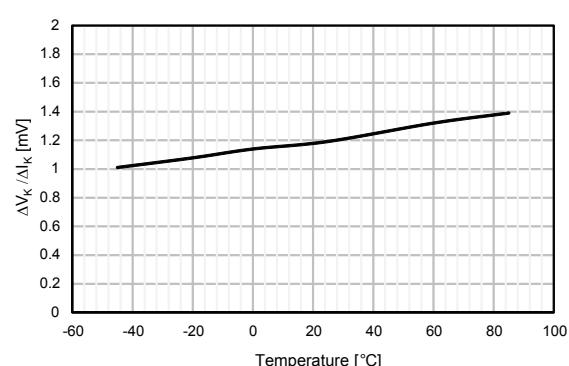


Figure 9. Minimum operating cathode current vs. temperature

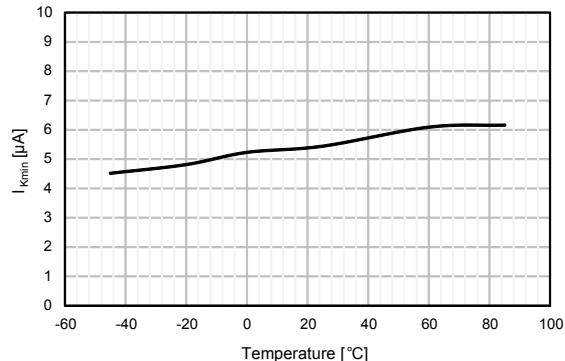


Figure 10. Reverse characteristic

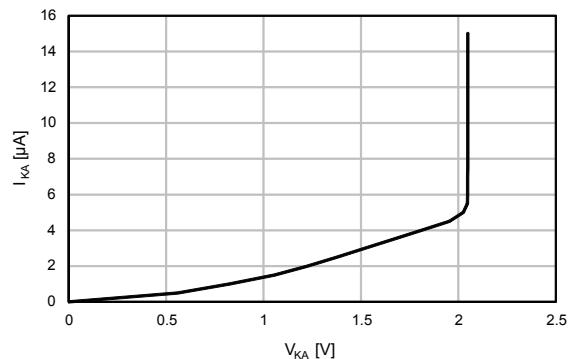


Figure 11. Forward characteristic

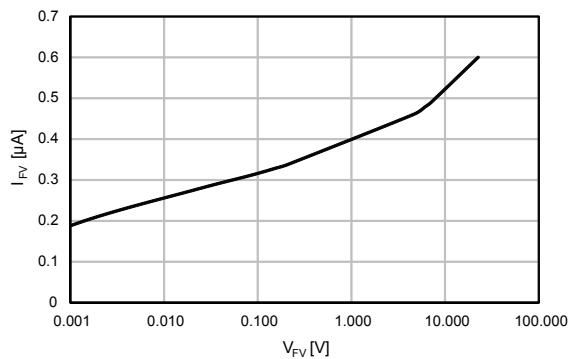


Figure 12. Temperature coefficient

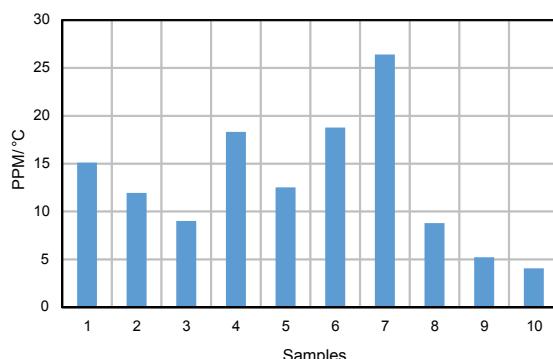


Figure 13. Turn-on transient ($t_{rise} = 10 \mu s$, no C_{out})

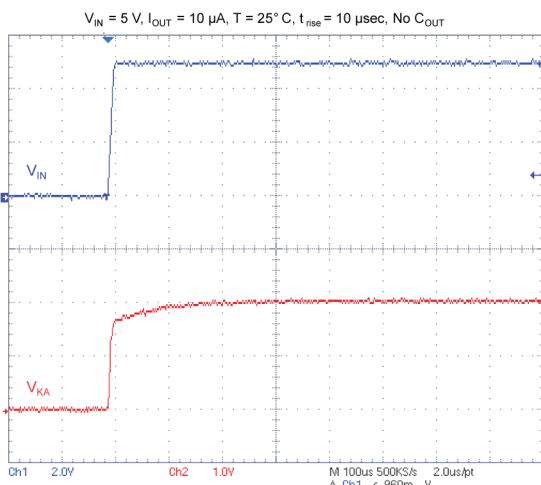
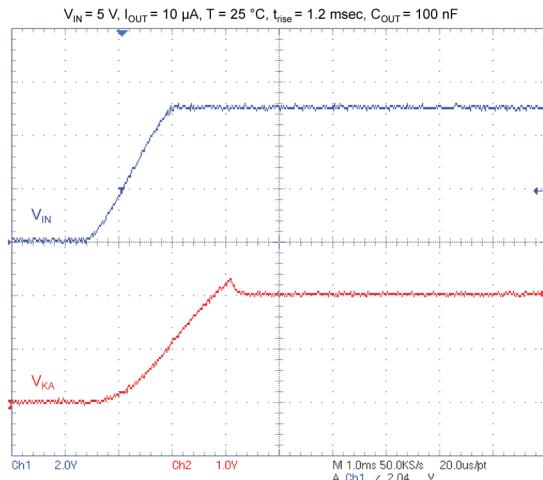
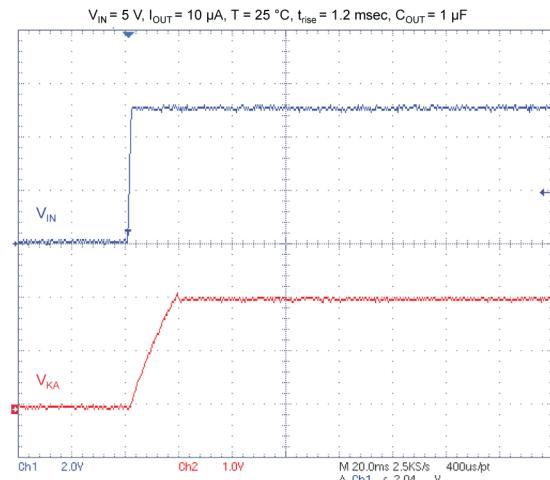


Figure 14. Turn-on transient ($t_{rise} = 1.2 \text{ ms}$, no C_{out})



Figure 15. Turn-on transient ($t_{rise} = 1.2 \text{ ms}$, $C_{OUT} = 100 \text{ nF}$)**Figure 16. Turn-on transient ($t_{rise} = 1.2 \text{ ms}$, $C_{OUT} = 1 \mu\text{F}$)**

6 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

6.1 SOT323-5L package information

Figure 17. SOT323-5L package outline

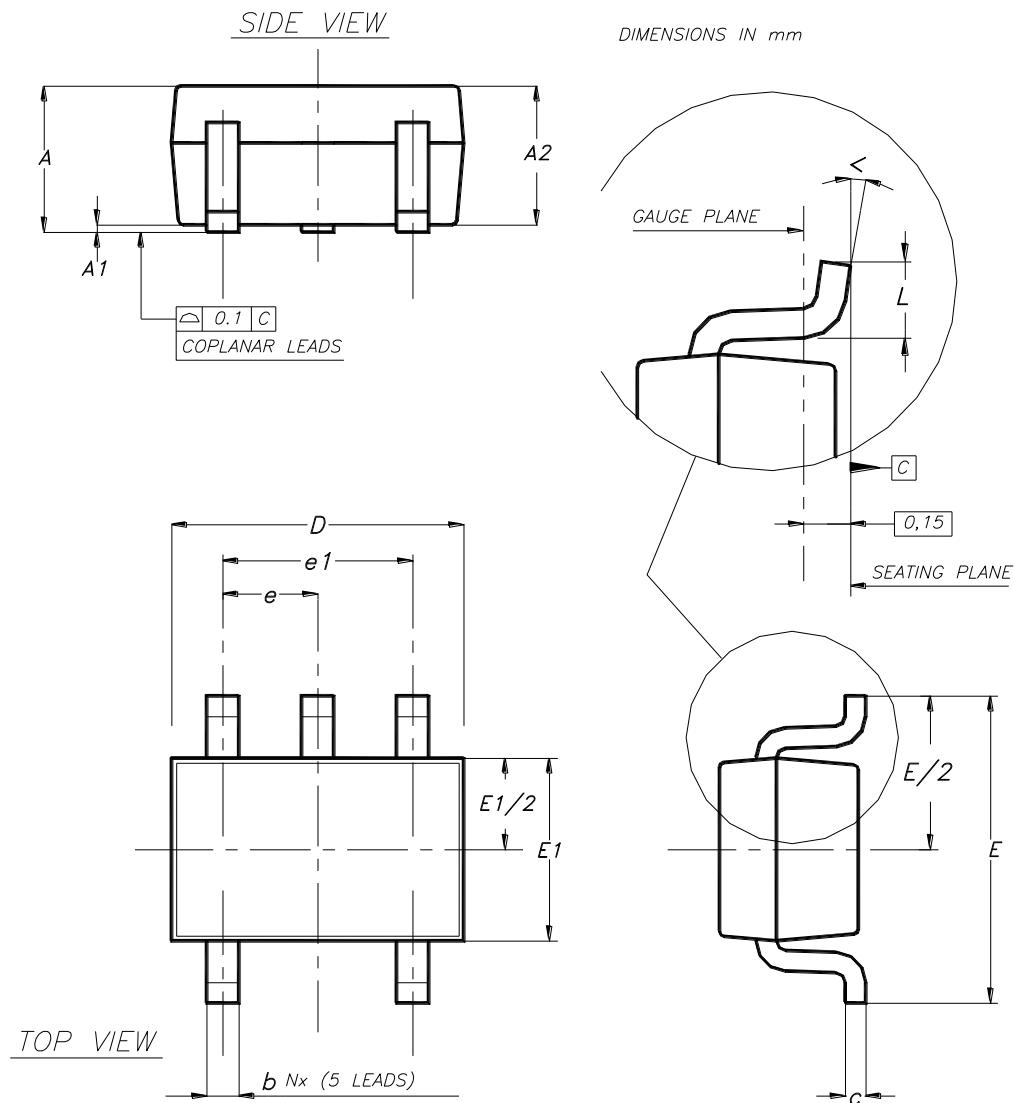


Table 6. SOT323-5L package mechanical data

Dim.	mm		
	Min.	Typ.	Max.
A	0.80		1.10
A1	0		0.10
A2	0.80	0.90	1.00
b	0.15		0.30
c	0.10		0.22
D	1.80	2.00	2.20
E	1.80	2.10	2.40
E1	1.15	1.25	1.35
e		0.65	
e1		1.30	
L	0.26	0.36	0.46
θ	0°		8°

Revision history

Table 7. Document revision history

Date	Revision	Changes
07-Jun-2018	1	Initial release.

Contents

1	Pin configuration	2
2	Maximum ratings	3
3	Typical application circuit	4
4	Electrical characteristics	5
5	Typical performance characteristics	6
6	Package information	9
	6.1 SOT323-5L package information	9
	Revision history	11

List of tables

Table 1.	Order code	2
Table 2.	Absolute maximum ratings	3
Table 3.	Thermal data.	3
Table 4.	Operating conditions	3
Table 5.	Electrical characteristics	5
Table 6.	SOT323-5L package mechanical data	10
Table 7.	Document revision history.	11

List of figures

Figure 1.	Pin connections (top view)	2
Figure 2.	Application circuit	4
Figure 3.	Cathode voltage vs. temperature ($I_K = 10 \mu A$)	6
Figure 4.	Cathode voltage vs. temperature ($I_K = 1 mA$)	6
Figure 5.	Cathode voltage vs. temperature ($I_K = 15 mA$)	6
Figure 6.	Static impedance vs. temperature	6
Figure 7.	$\Delta V_K / \Delta I_K$ vs. temperature ($I_K = 8 \mu A$ to $1 mA$)	6
Figure 8.	$\Delta V_K / \Delta I_K$ vs. temperature ($I_K = 1 mA$ to $15 mA$)	6
Figure 9.	Minimum operating cathode current vs. temperature	7
Figure 10.	Reverse characteristic	7
Figure 11.	Forward characteristic	7
Figure 12.	Temperature coefficient	7
Figure 13.	Turn-on transient ($t_{rise} = 10 \mu s$, no C_{OUT})	7
Figure 14.	Turn-on transient ($t_{rise} = 1.2 ms$, no C_{OUT})	7
Figure 15.	Turn-on transient ($t_{rise} = 1.2 ms$, $C_{OUT} = 100 nF$)	8
Figure 16.	Turn-on transient ($t_{rise} = 1.2 ms$, $C_{OUT} = 1 \mu F$)	8
Figure 17.	SOT323-5L package outline	9

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